

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	44.0773	N/A	86.4684
RT2	31.2189	N/A	127.1242
RT3	265.2248	N/A	117.3069
RT4	119.4790	N/A	19.1005
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	1.4079	N/A	572.6423 μ
CT2	147.3951 μ	N/A	5.2228 m
CT3	3.2833 m	N/A	2.8820 m
CT4	919.9911 μ	N/A	44.2333 μ

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ($^{\circ}\text{C}/\text{W}$)			
Junction to	Ambient	Case	Foot
RF1	100.3782	N/A	20.1651
RF2	251.2865	N/A	146.1682
RF3	71.8884	N/A	133.4933
RF4	36.4469	N/A	50.1734
Thermal Capacitance (Joules/ $^{\circ}\text{C}$)			
Junction to	Ambient	Case	Foot
CF1	227.1993 u	N/A	41.8899 u
CF2	1.4212 m	N/A	388.0249 u
CF3	19.6820 m	N/A	2.2720 m
CF4	2.1078	N/A	133.3266 u

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

